

Docket No.: P2002,0635

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : DIRK FUHRMANN ET AL.

Filed : CONCURRENTLY HEREWITH

Title : SEMICONDUCTOR MEMORY HAVING A CONFIGURATION OF  
MEMORY CELLS

INFORMATION DISCLOSURE STATEMENT

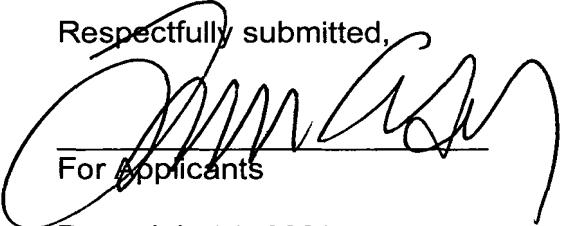
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In accordance with 37 C.F.R. 1.98 copies of the following patents and/or publications are submitted herewith:

U.S. Patent No. 6,448,600 B1 (Schlösser et al.), dated September 10, 2002, and corresponding German Patent DE 199 54 867 C1 (Schlösser et al.), dated December 7, 2000.

Respectfully submitted,

  
For Applicants

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Date: July 31, 2003

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/nt/kf

FORM PTO-1449 (SUBSTITUTE)		Attorney Docket No.: P2002,0635 Appl. No.: _____					
U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		Applicant: DIRK FUHRMANN ET AL.					
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))		Filing Date: July 31, 2003 Group Art Unit: _____					

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
	A	6,448,600 B1	9/10/02	Schlösser et al.			
	B						
	C						
	D						
	E						
	F						
	G						
	H						
	I						

## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES   NO
	J	199 54 867 C1	12/7/00	Germany			
	K						
	L						
	M						
	N						

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)


EXAMINER	DATE CONSIDERED